NSN 5961-01-069-3202

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-069-3202 **Inclosure Material:** Plastic **Overall Length:** 0.204 inches **Overall Diameter:** 0.188 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage, dc and 25.0 collector to emitter voltage, dc and 4.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 25.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 38.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No